

TOSHIBA Transistor Silicon PNP Triple Diffused Type (Darlington power transistor)

2SB1682

Unit: mm

- Power Amplifier Applications
- High-Power Switching Applications

- High-breakdown voltage: $V_{CEO} = -160 \text{ V (min)}$
- Complementary to 2SD2636

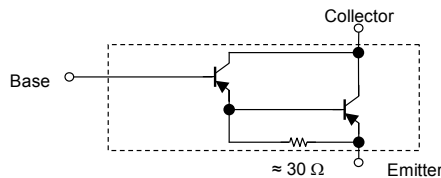
Maximum Ratings ($T_c = 25^\circ\text{C}$)

Characteristic Sy		mbol	Rating	Unit
Collector-base voltage		V_{CBO}	-160	V
Collector-emitter voltage		V_{CEO}	-160	V
Emitter-base voltage		V_{EBO}	-5	V
Collector current	DC I	C	-8	A
	Pulse I	CP	-15	
Base current		I_B	-1	A
Collector power dissipation		P_C	100 W	
Junction temperature		T_j	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	-55 to 150	$^\circ\text{C}$

1. Base	
2. Collector(heatsink)	
3. Emitter	
JEDEC	—
JEITA	—
TOSHIBA 2	-16C1A

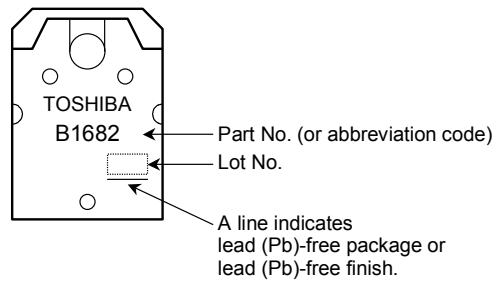
Weight: 4.7 g (typ.)

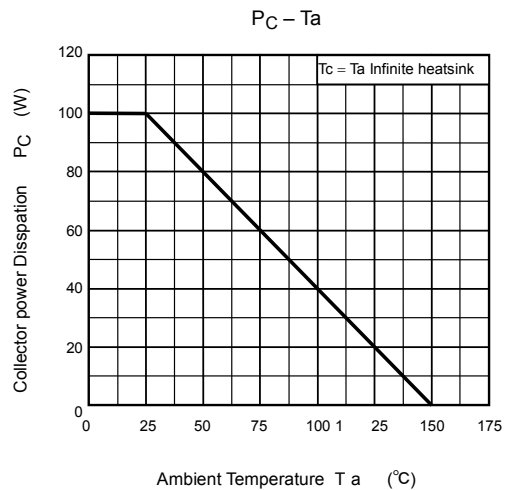
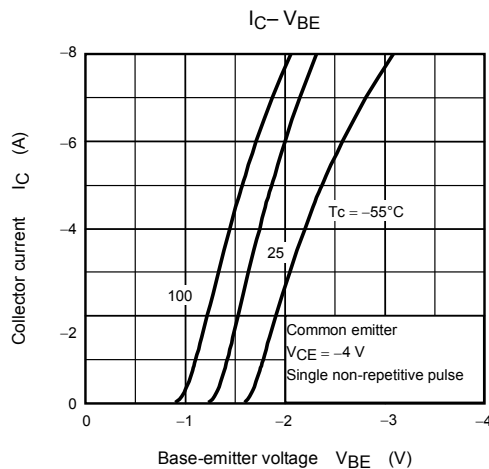
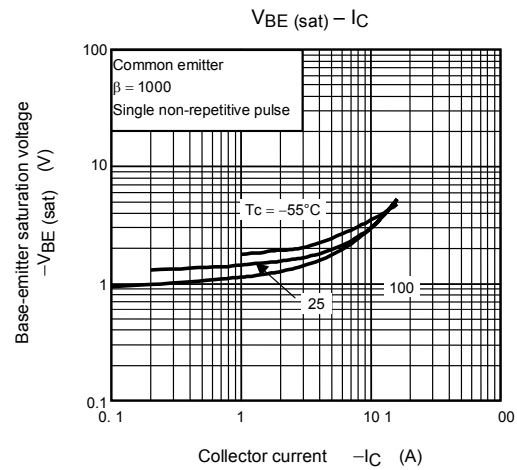
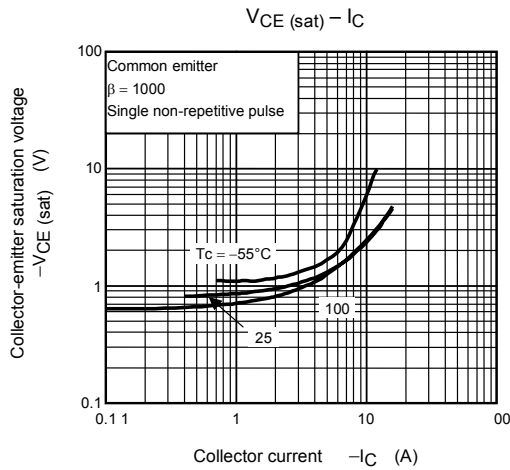
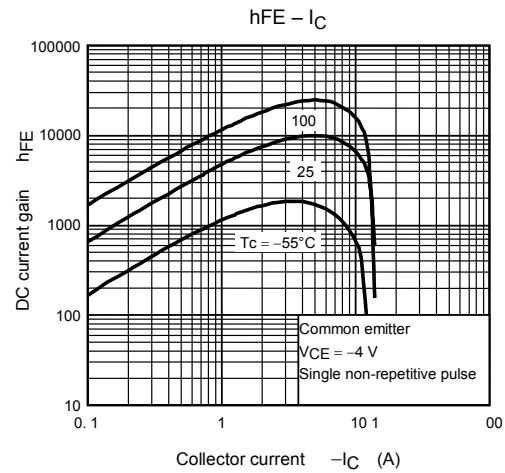
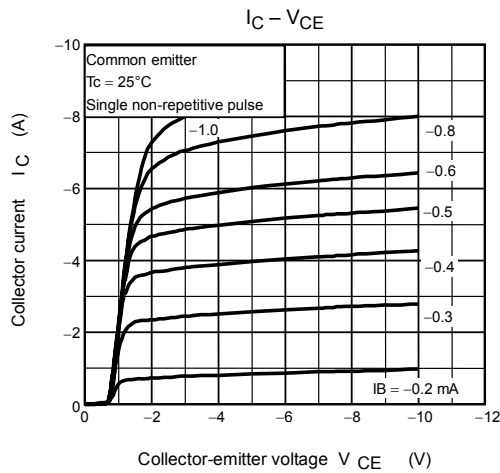
Equivalent Circuit

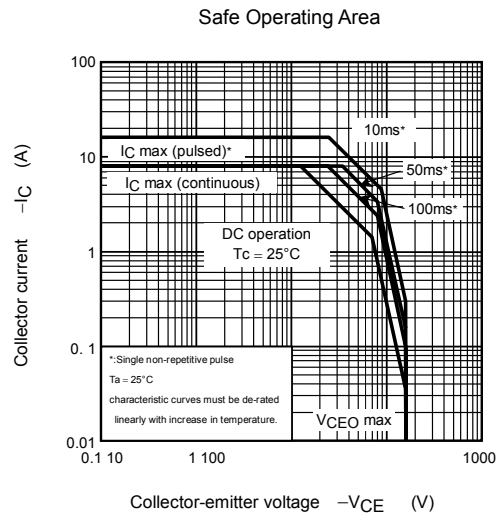


Electrical Characteristics ($T_c = 25^\circ\text{C}$)

Characteristic S		ymlbol	Test Conditions	Min	Typ.	Max	Unit
Collector cut-off current		I_{CBO}	$V_{CB} = -160 \text{ V}, I_E = 0$	—	—	-10	μA
Emitter cut-off current		I_{EBO}	$V_{EB} = -5 \text{ V}, I_C = 0$	—	—	-10	μA
Collector-emitter breakdown voltage		$V_{(BR) CEO}$	$I_C = -10 \text{ mA}, I_B = 0$	-160	—	— V	
DC current gain		$h_{FE} (1)$	$V_{CE} = -4 \text{ V}, I_C = -1 \text{ A}$	500	—	—	
		$h_{FE} (2)$	$V_{CE} = -4 \text{ V}, I_C = -7 \text{ A}$	5000	— 1	5000	
Collector-emitter saturation voltage		$V_{CE (sat)}$	$I_C = -7 \text{ A}, I_B = -7 \text{ mA}$	—	—	-3.0 V	
Base-emitter voltage		V_{BE}	$V_{CE} = -4 \text{ V}, I_C = -7 \text{ A}$	—	—	-3.0 V	
Transition frequency		f_T	$V_{CE} = -10 \text{ V}, I_C = -1 \text{ A}$	— 35	—	— MHz	z
Switching Time	Turn-on Time	t_{on}		— 0.	7	—	μs
	Storage Time	t_{stg}		— 1.	3	—	
	Fall Time	t_f		— 0.	7	—	

Marking





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